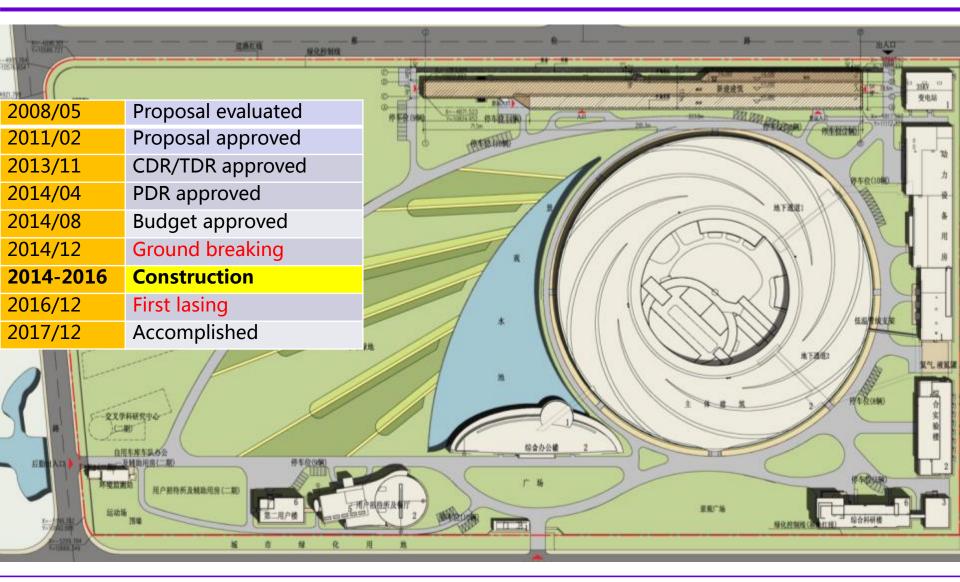
C-band acceleration RF system for SXFEL at SINAP Wencheng Fang, Qiang Gu, Jianhao Tan, Zhentang Zhao, SINAP 13 Jun, 2017, IFIC Valencia

Outline

- Background application in SXFEL
- Prototype test results
- Layout and installation of C-band RF system
- RF conditioning and beam test results.
- Upgrading plan for user facility
- Summary

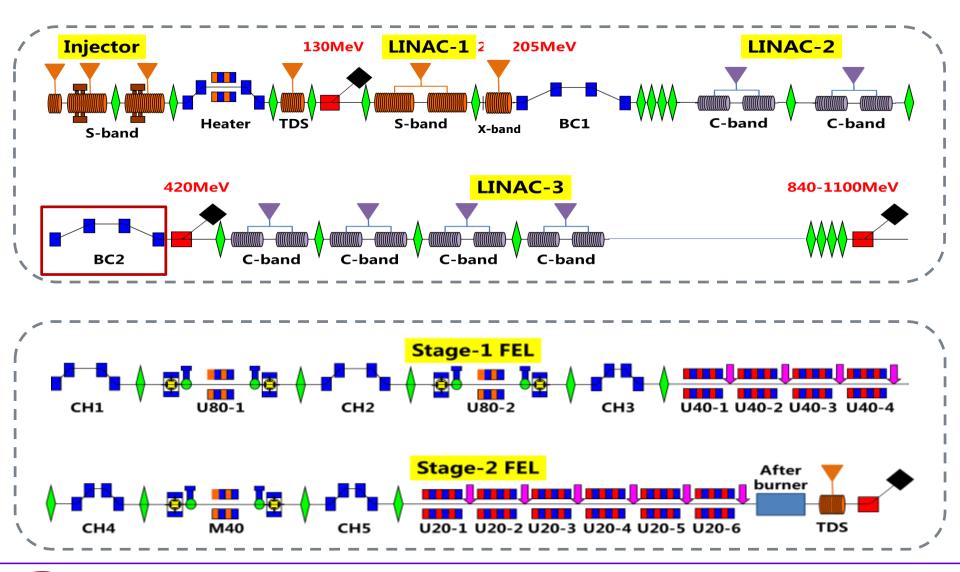
Shanghai Photon Science Center in Zhangjiang campus of SINAP



SXFEL layout plan at SINAP

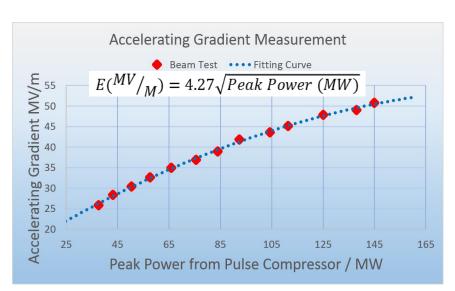


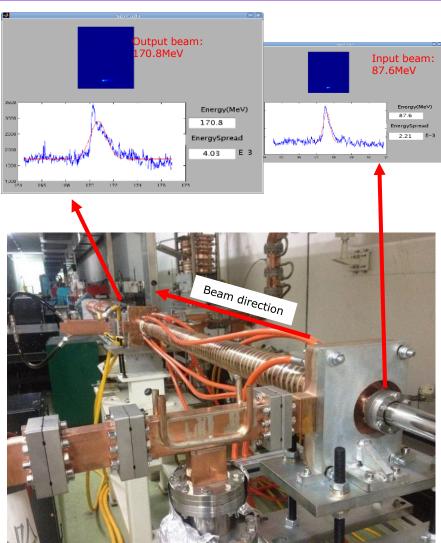
SXFEL test facility linac layout



Beam test results of Prototype (50.8MV/m maximum)

- 1. About more half month RF conditioning.
- 2. Beam energy is accelerated to maximum energy of 170.8MeV
- 3. 50.8MV/m maximum gradient is got, corresponding to effective length of 1.638m.
- 4. Different gradients are also measured.



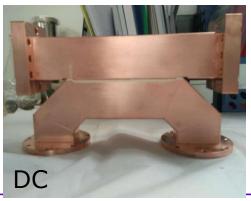


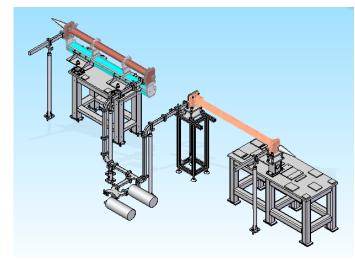
C-band RF unit prototype test results (Sep. 2016)







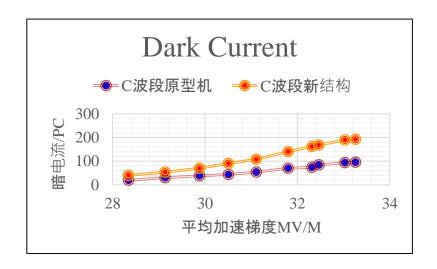


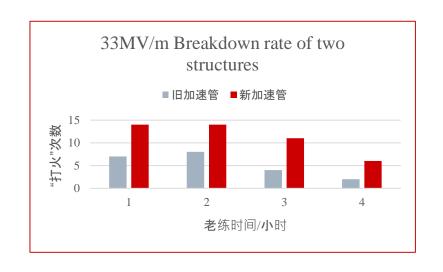




High power test results of RF unit

- C-band RF unit has been tested for 1 week, and reached 33MV/m accelerating gradient. Which power of klystron is about 30MW.
- 2. The new acc structure has two times than old structure on dark current and breakdown rate, maybe because time was not enough for RF conditioning of new acc structure.
- 3. Due to time and power limited, no further RF conditioning was proceeded for higher gradient.





C-band RF system for main linac

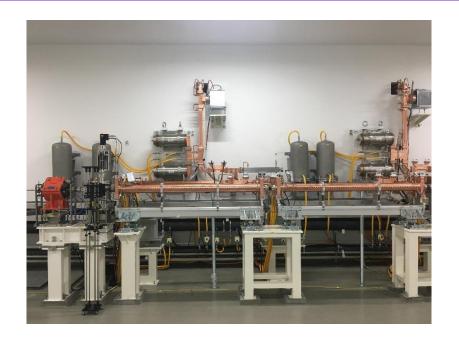
- 1. Totally there are 6 C-band RF units as main linac.
- 2. 6 klystrons, modulators and amplifiers as power source
- 3. 12 accelerating structures, 6 pulse compressor, and waveguides.
- 4. 3 boxes of LLRF based on MTCA 4.0, each box controls two RF units.



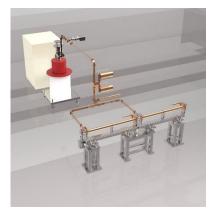


Layout of C-band unit

- 50MW C-band klystron is from Mitsubishi.
- 2. PFN-thyratron type modulator is developed at SINAP.
- 3. Acc, PC and waveguide is developed at SINAP
- 4. C-band load was made by Tsinghua University.
- 5. Low-level hardware system based on MTCA is from Struck company in Germany, and developed by SINAP.







C-band klystron PV-5050

- 1. All 7 C-band klystrons are from Mitsubishi.
- 2. 30MW power is required in the first step for 34MV/m.
- 3. 42MW power is required in the second step for 40MV/m.

Electrical specifications

| | Parameter | Rated value | |
|----|----------------------------------|-----------------|--|
| 1 | Frequency | 5712 MHz | |
| 2 | RF peak output power | 50 MW | |
| 3 | Voltage pulse width | 6.2μs | |
| 4 | RF pulse width | 2.5µs | |
| 5 | Peak beam voltage | 350kV | |
| 6 | Peak beam current | 320A | |
| 7 | Peak driver power | 130W (200W max) | |
| 8 | Pulse repetition frequency | 50Hz | |
| 9 | No spark time at nominal ratings | 2hours min | |
| 10 | Efficiency | 43%min | |
| 11 | Gain | 54dB min | |
| 12 | Heater voltage | 120V max | |
| 13 | Heater current | 4.5A max | |
| 14 | Heater power | 500W max | |
| 15 | Preheating time | 1hour | |
| 16 | Ion pump voltage | 3.0-5.0kV | |
| 17 | Ion pump current | 5μA max | |



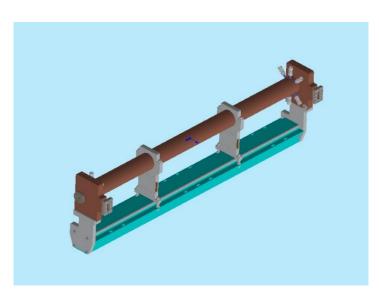
Modulator (PFN + Tharatron)

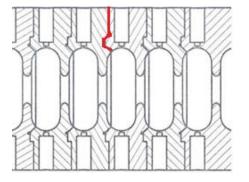
| Item | Value | Unit |
|---------------------------|----------|------|
| Pulse voltage | 350 | kV |
| Pulse current | 320 | A |
| Pulse power | 112 | MW |
| Pulse width (flat-top) | 3 | μs |
| FWHm | 5.5 | μs |
| Repetition rate | 10 | Hz |
| Average power | 7 | kW |
| Transformer ratio | 1:16 | |
| PFN voltage | 45 | kV |
| Switch current | 5200 | A |
| PFN type | 20 cells | |
| PFN impedance | 4.33 | Ω |
| PFN capacity | 0.635 | μF |
| Charging voltage | 50 | kV |
| Charging current | 480 | mA |
| Flatness | <±0.25 | % |
| Amplitude stability (rms) | < 0.02 | % |
| Rise edge jitter (rms) | < 10 | ns |



Accelerating structures

- 1. This structure is constant gradient, phase advance is 4pi/5, target is 40MV/m at least.
- 2. Rounded cell for higher impedance, and tuner is remained.
- 3. Compact coupler with single port, inner water cooling.
- 4. Four support points, in which one is fixed, two are flexible, and one is free.





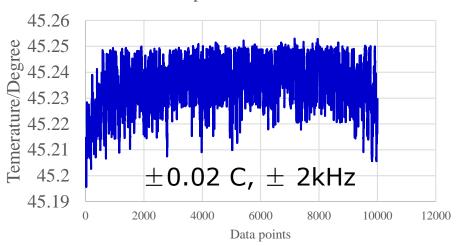




- 1. Pulse compressor was first tuned by mechanical tuner.
- 2. During operation, advanced Chiller are used to make temperature stable, and also to tune PD slightly.

| Frequency | 5712MHz |
|----------------------|--------------|
| Quality factor | About 180000 |
| Coupling coefficient | About 7.5 |

12 hours Temperature measurement



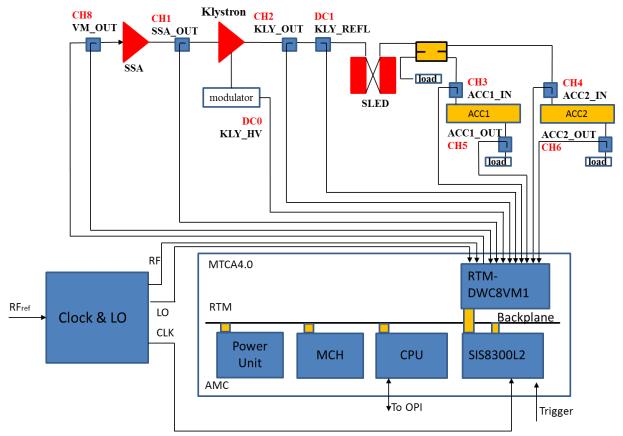






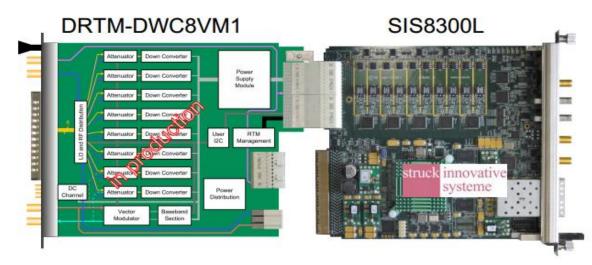
LLRF based on MTCA 4.0

- 1. LLRF system is based on MTCA 4.0 hardware and software driver, and was developed to carry out many functions, including amplitude and phase feedback and modulation, data acquisition and reflection protection.
- 2. 8 RF signals and 2 DC signals channels.
- 3. Each crate controls two C-band RF units.



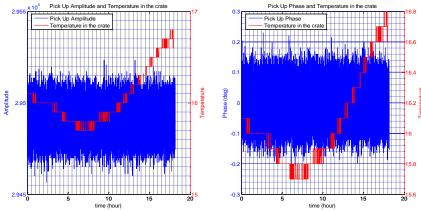


MicroTCA core: DRTM-DWC8VM1 and SIS8300L board



Struck SIS8300L Board

- RF signals acquisition.
- FPGA feedback control
- IQ signals output
- 10 channels 125 MHz 16-bit ADC
- 2 channels 250MHz 16-bit DACs
- Virtex 6 FPGA



Amplitude and phase stability with local master and Amplifier: 0.17% and 0.4 degree (peak-to-peak) for S-band

DRTM-DWC8VM1 Board

- 8 channels down-converter (700MHz-7GHz)
- Stability: amplitude<0.005%
- phase<10fs(rms)[10Hz,1MHz]
- 2 DC channels for coupling (DC-400MHz)
- One channel for up-converter (50MHz-4GHz)
- Tunable attenuator for RF input

Temperature control of cabinet and cable for LLRF

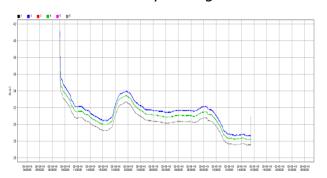
Heat insulating material

 28 ± 0.1 °c water tube



RF signal cable

Three locations for temperature measurement ± 0.1 °C stability during 29 hours

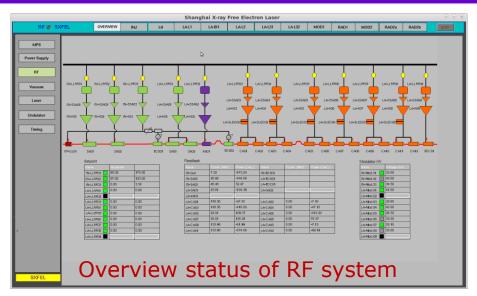


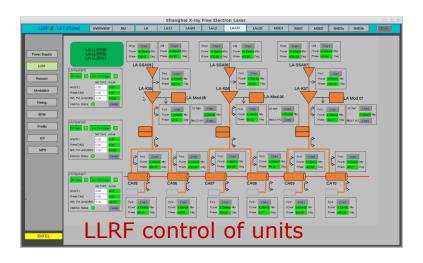


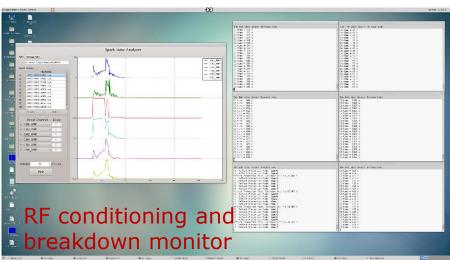
Three locations for humidity measurement $\pm 2.8\%$ stability during 29 hours

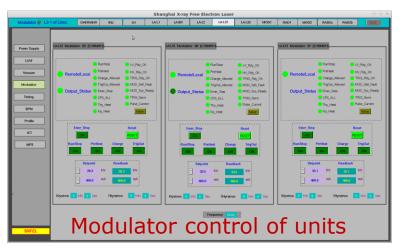


Control windows of RF system

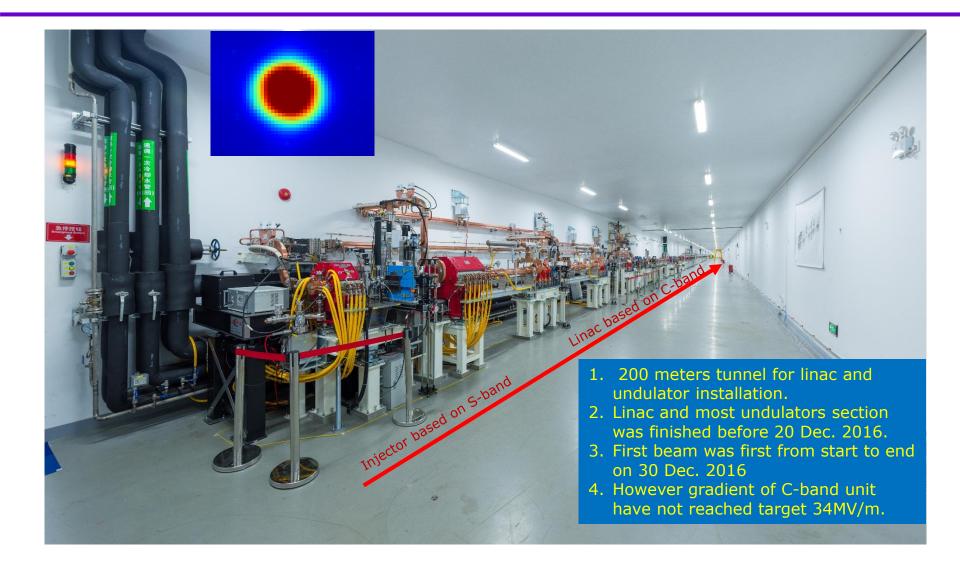




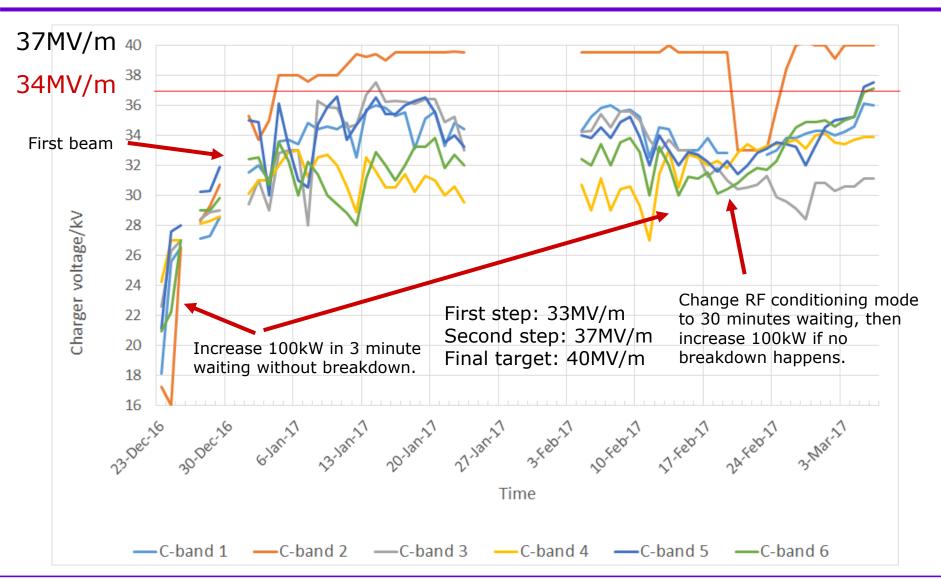




Present Status of SXFEL

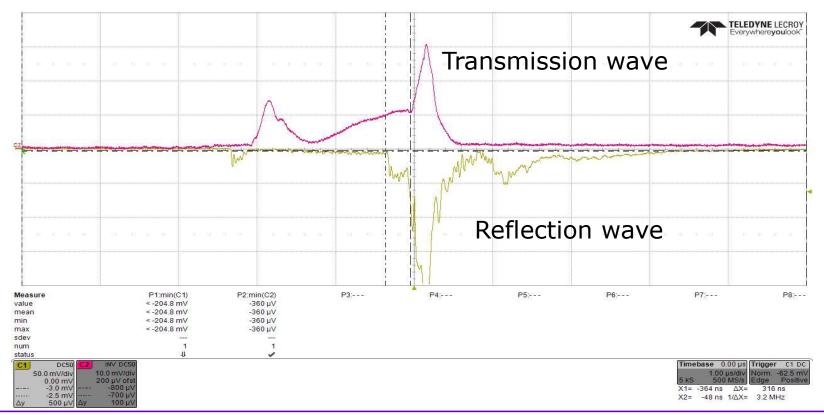


Problems on RF conditioning of C-band RF units



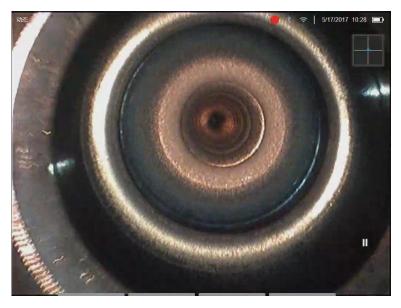
Limitation on accelerating gradient

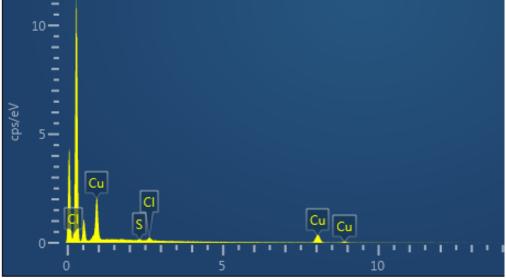
- 1. No breakdown location monitor system in this facility, so we use on oscillator oscilloscope to capture reflection wave and transmission wave.
- 2. All breakdowns happens in the upstream accelerating structure, in particular in the beginning end of this structure, because delay time between reflection rise and transmission is about 330ns, which is same as filling time.



Pollution from vacuum system

- 1. Five structures were removed from beam line, and checked by endoscope, and element analysis.
- 2. All beginning end of five structures looks black, and main element is Carbon (C), and moreover there exists Chlorine (Cl) and Sulfur (S). All these elements are proved from vacuum system finally.
- 3. Pollution expanded from vacuum system, and enter first structure of five units, inspires RF breakdown and leaves C, Cl and S on the surface of cells, which are easy to make RF breakdown in high gradient field.



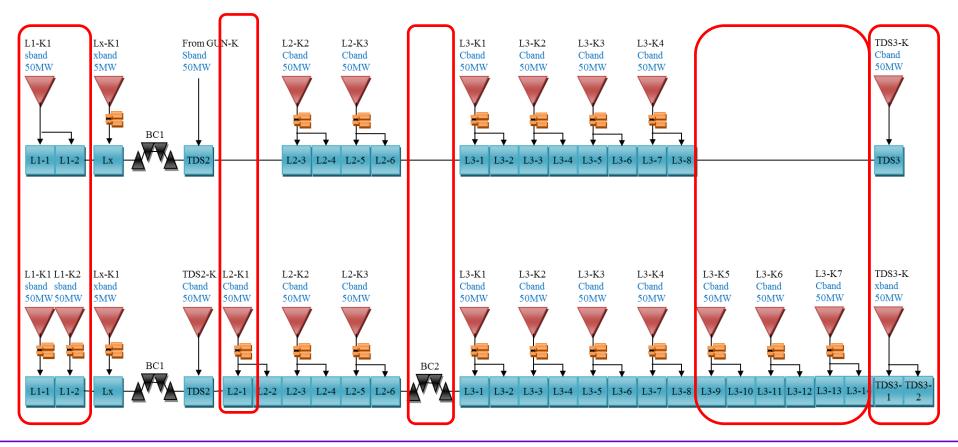


How to solve this serious problem?

- Re-clean vacuum system, including tubes, valves and profiles, in particular near C-band system.
- 2. Removing five polluted structures, and finding feasible methods to clean pollution on the cell surface. If it's impossible, we should make new five structures to replace them.
- 3. The rest of 7 structures are reassembled for three new RF units, and accelerate beam energy to low energy of 500MeV for FEL experiment first, and will boost to 840MeV after new structures arrival.
- 4. So far three new units have been re-conditioned, and reached 35MV/m at least, and will used for beam acceleration soon.

C-band RF system for SXFEL upgrading

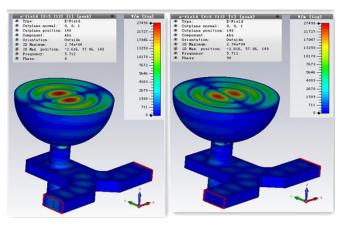
- Beam energy up to 1.5GeV from 0.84GeV
- 2. 4 new C-band RF unit will be added to the present facility.
- 3. Accelerating gradient of C-band RF unit will be up to 40MV/m from 32.5MV/m, klystron output power is up to power of 45MW.

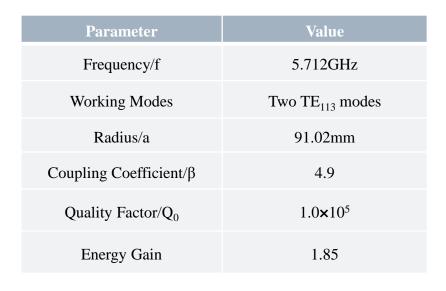


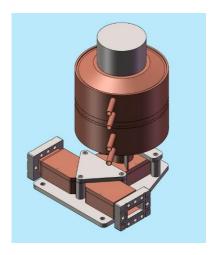
One spare scheme of spherical pulse compressor for user facility

- 1. Hybrid 3dB coupler, and spherical cavity for two polarized mode.
- 2. TE013 mode is used for compact sized relatively.
- 3. Mechanical design is finished and fixed, and is in the process of fabrication.
- 4. This structure is possible to replace SLED for user facility.

| Type: | 712) [1(1)] (peak) | V/= |
|--------------------------------|---------------------------------|---|
| Component: | E-Field Abs | 1149 |
| Orientation: | Outside | 1044 |
| 3D Maximum: 3D Max. nositio | 1149 on: 22.88, 70.42, 11.93 | 940 |
| Frequency: | 5.712 | 835 |
| Phase: | 0 | 791 |
| | | 100000 |
| | | 627 |
| | | 522 |
| | | 410 |
| | | 313 |
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Summary

- All C-band RF units have been installed in SXFEL, however RF conditioning of C-band met with serious problems, and five structure were polluted by vacuum system, which limits the accelerating gradient.
- Five polluted structures were removed, and rest seven structures are reassemble together to form new three C-band RF unit. So far 35MV/m gradient at least was carried out in this three new units, and will provide 500MeV beam for preliminary FEL experiments. In the future five new structures will replace old ones, and boost energy to 840MeV as soon as possible.
- Upgrading of SXFEL test facility has been started, and four new C-band RF units will be installed, and finally accelerating gradient is targeted on 37MV/m for 1.5 GeV or higher energy. New spherical pulse compressor will be one spare scheme for user facility.

